



PATENT  
Attorney Docket No.: SAM-0234

#101B  
4/11/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Sung-bae Park, *et al.*

Examiner: Lewis, M.

Serial No.: 09/924,787 ✓

Group Art Unit: 2822

Filed: August 8, 2001

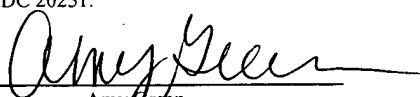
Title: SOI MOSFET HAVING BODY CONTACT FOR PREVENTING FLOATING  
BODY EFFECT AND METHOD OF FABRICATING THE SAME

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Assistant Commissioner for Patents, Washington, DC 20231.

3-18-03

Date

  
Amy Green

Assistant Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT B

Sir:

This is in response to the Office Action mailed on November 19, 2002. The applicant requests a one-month extension of the time allowed for response. A petition for the extension and the extension fee are enclosed.

Please amend the application as follows:

In the Claims

Please amend the claims as follows:

1. (Twice Amended) A silicon-on-insulator metal oxide semiconductor field effect transistor (SOI MOSFET) comprising:
- a semiconductor substrate;
  - a buried oxide layer formed on the semiconductor substrate;
  - a body on the buried oxide layer, the body being an active region of a transistor;

B1  
Sub C7

RECEIVED  
MAR 28 2003  
IC 2800 MAIL ROOM